

3 Phase PMSM/BLDC Motor Controller with Gate Driver

General Description

The RT7075 series is the two-in-one IC which consists of 3 phase motor controller and gate driver delicately designed for PMSM/BLDC motor applications.

RT7075 series integrates the ARM 32-bit Cortex-M0 core and peripheral circuits to perform a FOC and sensorless motor control. The IC has integrated various system level peripheral functions, such as ADC, DAC, communication interface, SVPWM, watchdog timer, current sensing, over current protection and over temperature protection, so as to reduce component count, board space and system cost. Furthermore, RT7075 series drives the external devices N-MOSFETs or IGBTs in a half-bridge configuration with an external bootstrap network up to 600V. A dead time control prevents shoot-through of the external devices. The RT7075 series is available in a LQFP-48L 7x7 package.

Applications

- PMSM/BLDC Motor
- Pedestal Fan
- Ceiling Fan
- Air Conditioner Indoor/Outdoor Fan
- Pump

Marking Information

	RT7075XGPL : Product Number
	YMDNN : Date Code
	GXYYY : Firmware Code

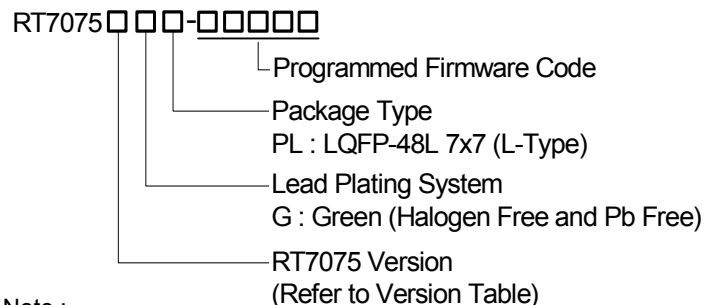
RT7075 Version Table

Version	RT7075A	RT7075B	RT7075C
Sourcing Current	290mA	125mA	70mA

Features

- Integrated 3 Phase PMSM/BLDC Controller with Gate Driver
- Sensorless, Sinewave Field Oriented Control
- Protections : OCP, UVLO and OTP
- PMSM/BLDC Motor Controller :
 - ▶ ARM 32-Bit Cortex-M0 CPU, Up to 60MHz
 - ▶ Memories Size : 16KB MTP, Internal ROM with embedded motor control library and 4KB SRAM
 - ▶ Power Management : Normal or Deep Sleep
 - ▶ Programming Soft-Start
 - ▶ Communication Interface : I²C and UART
 - ▶ Programmable Clock for PFC control
 - ▶ 10-Channel 10-Bit ADC
 - ▶ 1-Channel Current Type 6-Bit DAC
 - ▶ 1-Channel Voltage Type 8-Bit DAC
- Gate Driver :
 - ▶ Floating Channel Designed for Bootstrap Operation up to 600V
 - ▶ Sourcing/Sinking Current :
 - RT7075A : 290mA/600mA
 - RT7075B : 125mA/600mA
 - RT7075C : 70mA/600mA
 - ▶ Built-In UVLO Functions for All Channels
 - ▶ Matched Propagation Delays for All Channels
 - ▶ V_{V15V} and V_{VBU/VW} Supply Range : 13V to 20V
 - ▶ Shoot-Through Prevention

Ordering Information



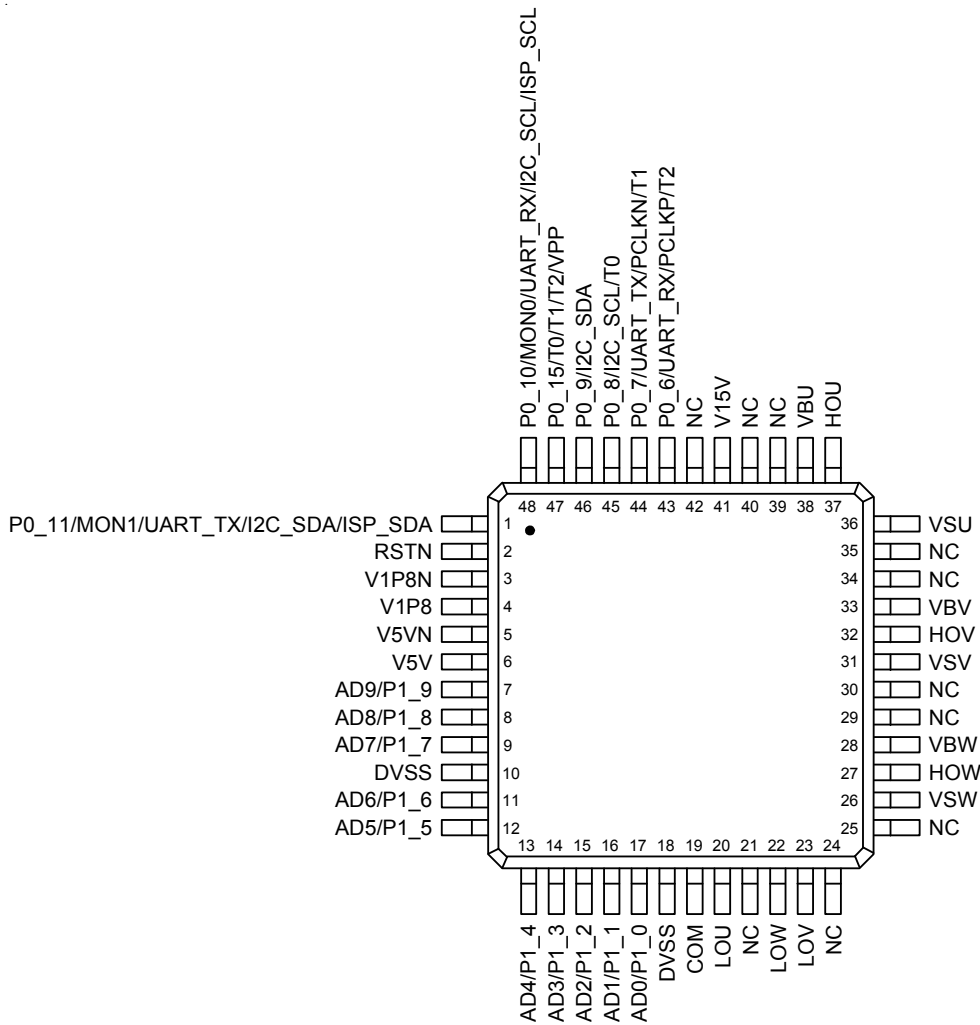
Note :

Richtek products are :

- ▶ RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- ▶ Suitable for use in SnPb or Pb-free soldering processes.

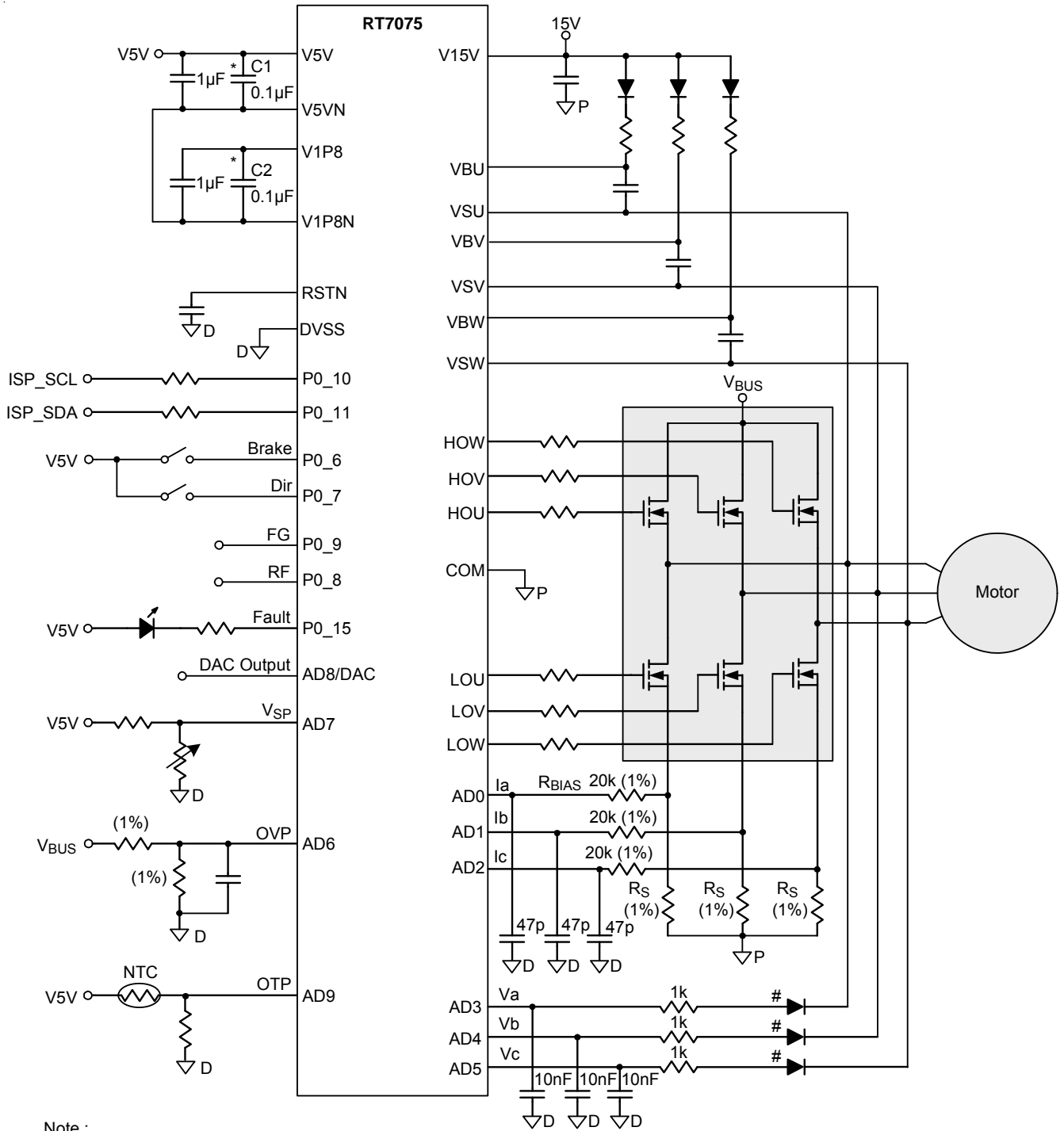
Pin Configuration

(TOP VIEW)



LQFP-48L 7x7

Typical Application Circuit



Note :

- 1. C1 & C2 as close as possible to the IC.
- 2. * : Option
- 3. # : General-purpose diodes, but pay attention to the voltage stress for different operating voltage of the motor.

Functional Pin Description

Pin No.	Pin Name	Type	Pin Function
1	P0_11	DIO	Pin 11 of GPIO port 0.
	MON1	DO	Internal digital signal monitoring output pin.
	UART_TX	DO	UART transmitting pin.
	I2C_SDA	DIO	I ² C data pin.
	ISP_SDA	DIO	In system programming data input pin.
2	RSTN	DI	Pad reset pin.
3	V1P8N	GND	1.8V power pin negative terminal.
4	V1P8	P	1.8V power pin.
5	V5VN	GND	5V power pin negative terminal.
6	V5V	P	5V power pin.
7	AD9	AIO	ADC Channel 9 input pin.
	AD9	AIO	Current type DAC input pin. (Sink type)
	P1_9	DIO	Pin 9 of GPIO port 1.
8	AD8	AIO	ADC Channel 8 input pin.
	AD8	AIO	Voltage type DAC output pin.
	P1_8	DIO	Pin 8 of GPIO port 1.
9	AD7	AIO	ADC Channel 7 input pin.
	P1_7	DIO	Pin 7 of GPIO port 1.
10	DVSS	GND	Digital ground.
11	AD6	AIO	ADC Channel 6 input pin.
	P1_6	DIO	Pin 6 of GPIO port 1.
12	AD5	AIO	ADC Channel 5 input pin.
	P1_5	DIO	Pin 5 of GPIO port 1.
13	AD4	AIO	ADC Channel 4 input pin.
	P1_4	DIO	Pin 4 of GPIO port 1.
14	AD3	AIO	ADC Channel 3 input pin.
	P1_3	DIO	Pin 3 of GPIO port 1.
15	AD2	AIO	ADC Channel 2 input pin.
	P1_2	DIO	Pin 2 of GPIO port 1.
16	AD1	AIO	ADC Channel 1 input pin.
	P1_1	DIO	Pin 1 of GPIO port 1.
17	AD0	AIO	ADC Channel 0 input pin.
	P1_0	DIO	Pin 0 of GPIO port 1.
18	DVSS	GND	Digital ground.
19	COM	PGND	Gate driver power ground.

Pin No.	Pin Name	Type	Pin Function
20	LOU	HVO	Low-side gate control signal of Phase A.
21, 42	NC	--	No internal connection.
22	LOW	HVO	Low-side gate control signal of Phase C.
23	LOV	HVO	Low-side gate control signal of Phase B.
24, 25, 29, 30, 34, 35, 39, 40	NC	--	For H-V rule.
26	VSW	HVI	High-side floating supply offset voltage of Phase C.
27	HOW	HVO	High-side gate control signal of Phase C.
28	VBW	HVI	High-side floating supply voltage of Phase C.
31	VSV	HVI	High-side floating supply offset voltage of Phase B.
32	HOV	HVO	High-side gate control signal of Phase B.
33	VBV	HVI	High-side floating supply voltage of Phase B.
36	VSU	HVI	High-side floating supply offset voltage of Phase A.
37	HOU	HVO	High-side gate control signal of Phase A.
38	VBU	HVI	High-side floating supply voltage of Phase A.
41	V15V	P	15V power pin.
43	P0_6	DIO	Pin 6 of GPIO port 0.
	UART_RX	DI	UART receiving pin.
	PCLKP	DO	Programmable clock positive output pin.
	T2	DI	T2 external enable or external clock input pin.
44	P0_7	DIO	Pin 7 of GPIO port 0.
	UART_TX	DO	UART transmitting pin.
	PCLKN	DO	Programmable clock negative output pin.
	T1	DI	T1 external enable or external clock input pin.
45	P0_8	DIO	Pin 8 of GPIO port 0.
	I2C_SCL	DIO	I ² C clock pin.
	T0	DI	T0 external enable or external clock input pin.
46	P0_9	DIO	Pin 9 of GPIO port 0.
	I2C_SDA	DIO	I ² C data pin.
47	P0_15	DIO	Pin 15 of GPIO port 0.
	T0	DI	T0 external enable or external clock input pin.
	T1	DI	T1 external enable or external clock input pin.
	T2	DI	T2 external enable or external clock input pin.
	VPP	P	8V input power for MTP fast programming.

Pin No.	Pin Name	Type	Pin Function
48	P0_10	DIO	Pin 10 of GPIO port 0.
	MON0	DO	Internal digital signal monitoring output pin.
	UART_RX	DI	UART receiving pin.
	I2C_SCL	DIO	I ² C clock pin.
	ISP_SCL	DI	In system programming clock input pin.

IO Type Definition :

DIO : Digital input/output pin.

DI : Digital input pin.

DO : Digital output pin.

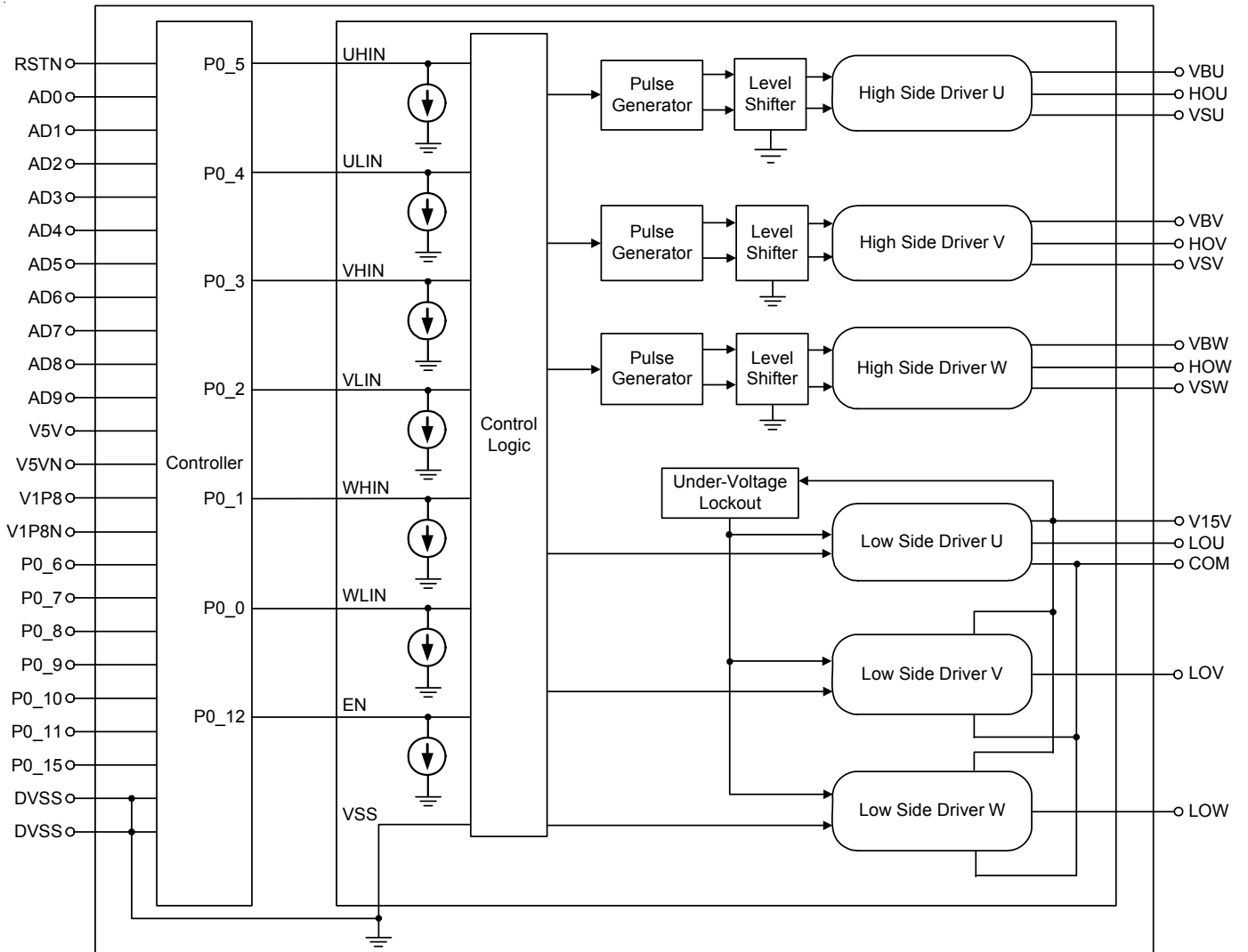
AIO : Analog input/output pin.

P : Power pin.

HVI : High voltage input pin.

HVO : High voltage output pin.

Functional Block Diagram



Absolute Maximum Ratings (Note 1)

• Supply Input Voltage, V15V -----	-0.3V to 25V
• Supply Input Voltage, V5V -----	-0.3V to 6.5V
• VSU/V/W to DVSS -----	-0.3V to 625V
• VBU/V/W to VSU/V/W, VBU/V/W -----	-0.3V to 25V
• HOU/V/W to VSU/V/W -----	-0.3V to (V _{VBU/V/W} + 0.3V)
• LOU/V/W to DVSS -----	-0.3V to (V _{V15V} + 0.3V)
• Allowable VSU/V/W Voltage Slew Rate, dVSU/V/W /dt -----	-50V/ns to 50V/ns
• Voltage of I/O Pin and RSTN Pin with Respect to GND -----	-0.2V to V _{V5V} + 0.2V
• Analog Input Voltage, VAN -----	-0.2V to V _{V5V} + 0.2V
• Power Dissipation, P _D @ T _A = 25°C	
LQFP-48L 7x7 -----	1.49W
• Package Thermal Resistance (Note 2)	
LQFP-48L 7x7, θ _{JA} -----	67°C/W
• Junction Temperature -----	150°C
• Lead Temperature (Soldering, 10 sec.) -----	260°C
• Storage Temperature Range -----	-65°C to 150°C
• ESD Susceptibility (Note 3)	
HBM (Human Body Model)	
Except HV Pin -----	2kV
HV (VBU/HOU/VSU, VBV/HOV/VSU, VBW/HOV/VSU) to GND -----	1kV

Recommended Operating Conditions (Note 4)

• Supply Voltage, V _{V15V} -----	13V to 20V
• VBU/V/W to VSU/V/W, VBSx -----	13V to 20V
• VSU/V/W to DVSS -----	0 to 600V
• HOU/V/W to VSU/V/W -----	0 to VBSx
• LOU/V/W to DVSS -----	0 to V _{V15V}
• Supply Input Voltage, V _{V5V} -----	4.5V to 5.5V
• Input Voltage for MTP Fast Programming, V _{VPP} -----	8V to 8.2V
• LDO capacitor on V1P8 -----	1μF
• Minimum time period of RSTN, T _{RSTN} -----	100μs
• Junction Temperature Range -----	-40°C to 125°C
• Ambient Temperature Range -----	-40°C to 105°C

Electrical Characteristics

($V_{V15V} = V_{VBU/VW} = 15V$, $V_{V5V} = 5V$, $T_A = 25^\circ C$, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Clock Section						
System Frequency	f _{SCLK}		58.8	60	61.2	MHz
Slow Clock for Sleep Mode	f _{LCLK}		77.6	80	82.4	kHz
Power Management Section						
Turn-On Voltage of V5V	V _{V5V_ON}		--	4.15	--	V
V5V On-Off Hysteresis	V _{V5V_hys}	Turn-Off Voltage = V _{V5V_ON} - V _{V5V_hys}	--	0.3	--	V
LDO Output for Internal Operation Voltage	V _{V1P8}	Full speed operation w/i external 20mA sink, C _{V1P8} > 1μF	--	1.8	--	V
V5V Current at Operation Mode	I _{V5V_OPER}	Typical sensor-less motor control library	--	18	--	mA
V5V Current at Deep Sleep Mode	I _{V5V_DSLP}		--	400	--	μA
ADC Section (0V to 4V, 10-bit, single end mode, gain = 1) (Note 5)						
ADC Input Voltage Range	V _{ADCIN}		0	--	4	V
VDAC Section (0V to 4V, 8-bit for short and over current) (Note 5)						
Minimum Conversion Voltage	V _{O_MIN}		--	0	--	V
Maximum Conversion Voltage	V _{O_MAX}		--	4	--	V
DAC Offset	V _{OFFSET}		--	2	--	LSB
Output Resistance of DAC	R _O	(Note 7)	--	5k	--	Ω
Integral Linearity Error	E _{INL}		-1	--	+1	LSB
Differential Linearity Error	E _{DNL}		-1	--	+1	LSB
VDAC Section (0V to 3V, 8-bit for general purposed comparator) (Note 5)						
Minimum Conversion Voltage	V _{O_MIN}		--	0	--	V
Maximum Conversion Voltage	V _{O_MAX}		--	3	--	V
DAC Offset	V _{OFFSET}		--	2	--	LSB
Output Resistance of DAC	R _O	(Note 7)	--	5k	--	Ω
Integral Linearity Error	E _{INL}		-1	--	+1	LSB
Differential Linearity Error	E _{DNL}		-1	--	+1	LSB
IDAC Section (0 to 126μA, 6-Bit for current sink) (Note 5)						
IDAC Output Bias Voltage Range	V _{BIAS}		0.2	--	5	V
Minimum Sink Current	I _{O_MIN}	V _{BIAS} = 2.5V	--	0	--	μA
Maximum Sink Current	I _{O_MAX}	V _{BIAS} = 2.5V	--	126	--	μA
Average Current Step	I _{LSB}	Test : (I _{I_MIN} - I _{I_MAX})/(256-1)	--	2	--	μA
DAC Offset	I _{OFFSET}		--	0	--	μA
Integral Linearity Error	E _{INL}		-3	--	+3	LSB
Differential Linearity Error	E _{DNL}		-1	--	+1	LSB

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Current Limit Comparator Section (Short and Over-Current)						
Comparator Offset	V _{OFFSET}	(Note 6)	-10	0	10	mV
Input Voltage Range of Comparator	V _{IN}	(Note 7)	1	--	4	V
Over-Current Level Range	V _{OC}	(Note 7)	0.5	--	4	V
General Purposed Comparator (Note 6)						
Comparator Offset	V _{OFFSET}		-5	0	5	mV
Input Voltage Range of Comparator	V _{IN}		0	--	3	V
IO of P0_6 to P0_7 Section						
Input High Voltage	V _{IH}		--	--	0.7 x V5V	V
Input Low Voltage	V _{IL}		0.3 x V5V	--	--	V
Pull-Down Resistor	R _{DOWN}		--	90	--	kΩ
High Level Output Current	I _{OH}	@ 0.8xV5V	--	15	--	mA
Low Level Output Current	I _{OL}	@ 0.2xV5V	--	15	--	mA
IO of P0_8 to P0_11 section						
Input High Voltage	V _{IH}		--	--	0.7 x V5V	V
Input Low Voltage	V _{IL}		0.3 x V5V	--	--	V
Pull-Up Resistor	R _{UP}		--	70	--	kΩ
High Level Output Current	I _{OH}	@ 0.8xV5V	--	15	--	mA
Low Level Output Current	I _{OL}	@ 0.2xV5V	--	15	--	mA
IO of AD0 to AD9 section and P0_15						
Input High Voltage	V _{IH}		--	--	2.7	V
Input Low Voltage	V _{IL}		0.6	--	--	V
Current Source for External Bias	I _{BIAS1}	AD0 to AD2	95	100	105	μA
Current Source for External Bias	I _{BIAS2}	AD3 to AD9	--	50	--	μA
Low Level Output Current	I _{OL}	AD0 to AD9	--	2	--	mA

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit	
Low Side Power Supply Section							
V15V Under-Voltage Lockout Threshold (On)	V_{THON_V15V}		9	10.5	12	V	
V15V Under-Voltage Lockout Threshold (Off)	V_{THOFF_V15V}		8	9.5	11	V	
V15V Under-Voltage Lockout Hysteresis	V_{HYS_V15V}		--	1	--	V	
V15V Quiescent Current	I_{Q_V15V}	Gate driver output low.	--	1000	--	μA	
V15V Operating Current	I_{P_V15V}	$f_{xLIN} = 20kHz$, HOU/V/W & LOU/V/W = Open	--	1000	--	μA	
Bootstrapped Power Supply Section							
VBU/V/W-VSU/V/W Under-Voltage Lockout Threshold (On)	V_{THON_VBSX}		9	10.5	12	V	
VBU/V/W-VSU/V/W Under-Voltage Lockout Threshold (Off)	V_{THOFF_VBSX}		8	9.5	11	V	
VBU/V/W-to-VSU/V/W Quiescent Current for Each Channel	I_{Q_VBSX}	Gate driver output low.	--	100	200	μA	
VBU/V/W-VSU/V/W Under-Voltage Lockout Hysteresis	V_{HYS_VBSX}		--	1	--	V	
VSU/V/W Leakage Current	I_{Vsx}	$V_{BU/V/W} = V_{SU/V/W} = 600V$	--	--	80	μA	
VBU/V/W-to-VSU/V/W Operating Current	I_{P_VBSX}	$f_{xHIN} = 20kHz$, HOU/V/W and LOU/V/W = Open	--	--	600	μA	
Gate Driver Output Section (HOU/V/W, LOU/V/W)							
High Side / Low Side Output Voltage	V_{OH}	$I_O = 0mA$, $V_{VBU/V/W} - V_{HOU/V/W}$, $V_{15V} - V_{LOU/V/W}$	--	50	200	mV	
	V_{OL}	$I_O = 0mA$, $V_{HOU/V/W} - V_{VSU/V/W}$, $V_{LOU/V/W} - V_{COM}$	--	20	100	mV	
HOU/V/W and LOU/V/W Sourcing Current	IO+	Gate driver output high, $V_{HOU/V/W} = V_{LOU/V/W} = 0V$, $PW < 10\mu s$ (Note7)	RT7075A	--	290	--	mA
			RT7075B	--	125	--	
			RT7075C	--	70	--	
HOU/V/W and LOU/V/W Sinking Current	IO-	Gate driver output low, $V_{HOU/V/W} = V_{LOU/V/W} = V_{V15V}$, $PW < 10\mu s$ (Note7)	--	600	--	mA	

Dynamic Electrical Characteristics

($V_{V15V} = V_{VBU/VW} = 15V$, $V_{V5V} = 5V$, $V_{VSU/VW} = GND$, $C_L = 1000pF$, $T_A = 25^\circ C$, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Turn-On Propagation Delay	t _{ON}	V _{VSX} = 0V	350	500	650	ns
Turn-Off Propagation Delay	t _{OFF}	V _{VSX} = 0V	350	500	650	ns
Gate Driver Output Turn-On Rising Time	t _R	RT7075A	--	70	--	ns
		RT7075B	--	250	--	
		RT7075C	--	450	--	
Gate Driver Output Turn-Off Falling Time	t _F		--	35	--	ns
Gate Driver Output Dead Time	DT		400	500	600	ns
Delay Matching	MT		--	--	120	ns
Dead-Time Matching to All Channels	MDT		--	--	120	ns

Note 1. Stresses beyond those listed “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Note 2. θ_{JA} is measured under natural convection (still air) at $T_A = 25^\circ C$ with the component mounted on a high effective-thermal-conductivity four-layer test board on a JEDEC 51-7 thermal measurement standard.

Note 3. Devices are ESD sensitive. Handling precaution is recommended.

Note 4. The device is not guaranteed to function outside its operating conditions.

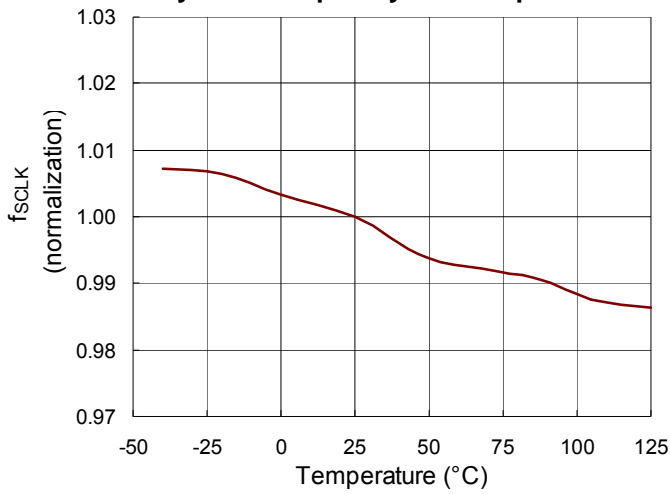
Note 5. Characterized, not tested at manufacturing.

Note 6. For comparator only.

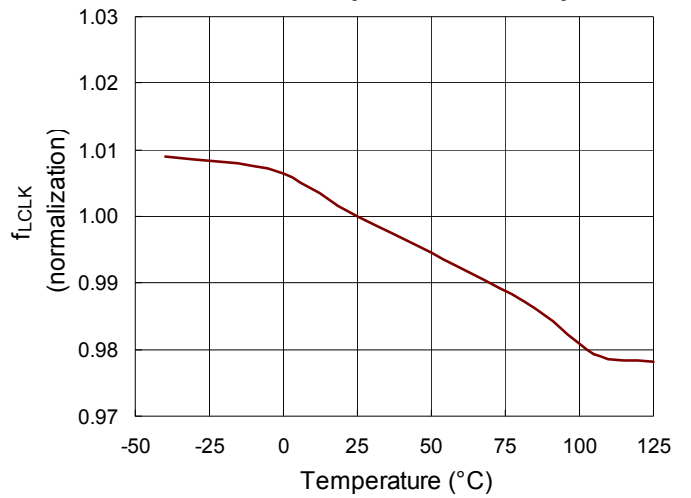
Note 7. This parameter is guaranteed by design.

Typical Operating Characteristics

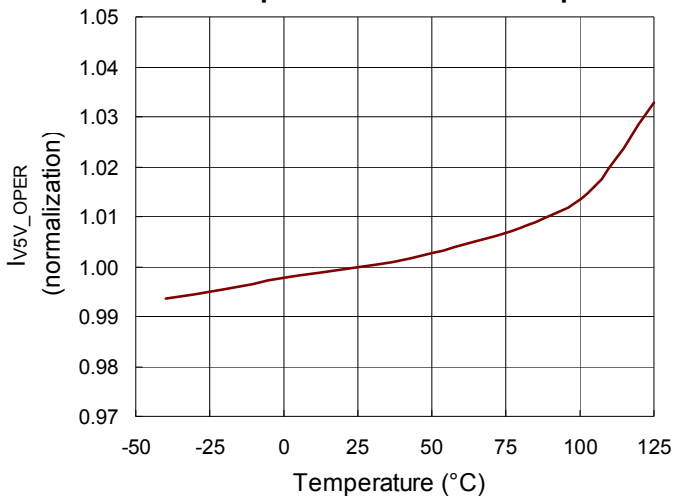
System Frequency vs. Temperature



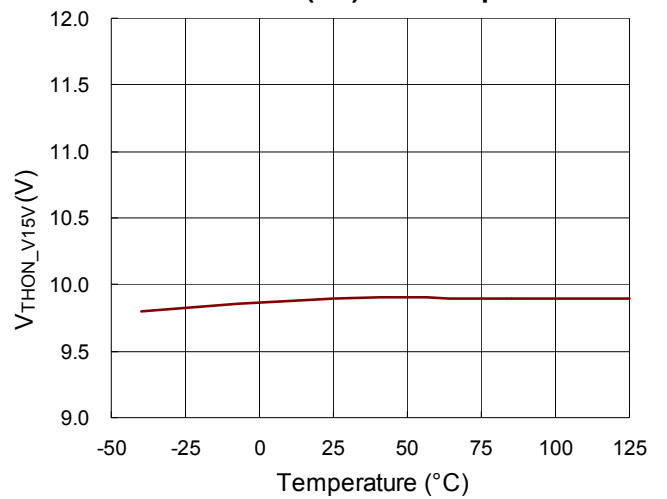
Slow Clock for Sleep Mode vs. Temperature



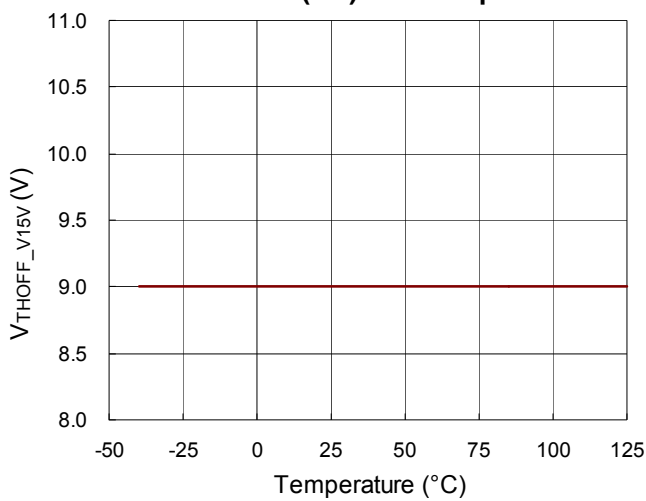
V5V Current at Operation Mode vs. Temperature



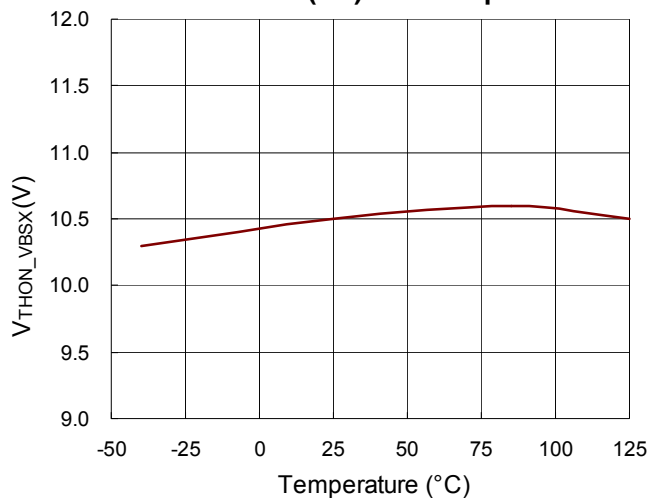
V15V UVLO (On) vs. Temperature

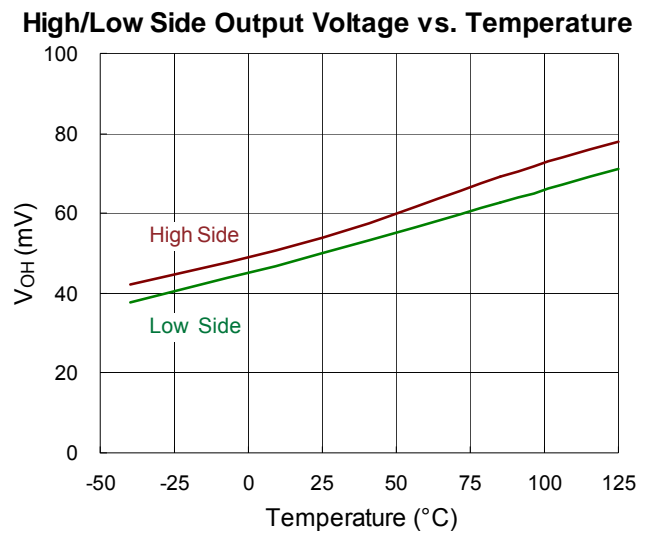
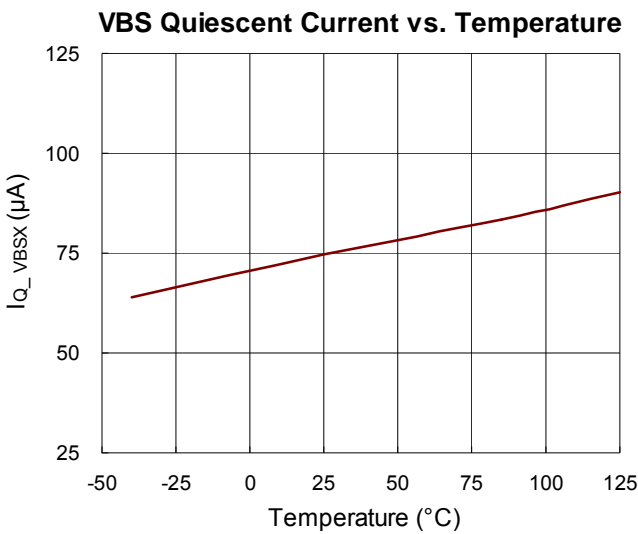
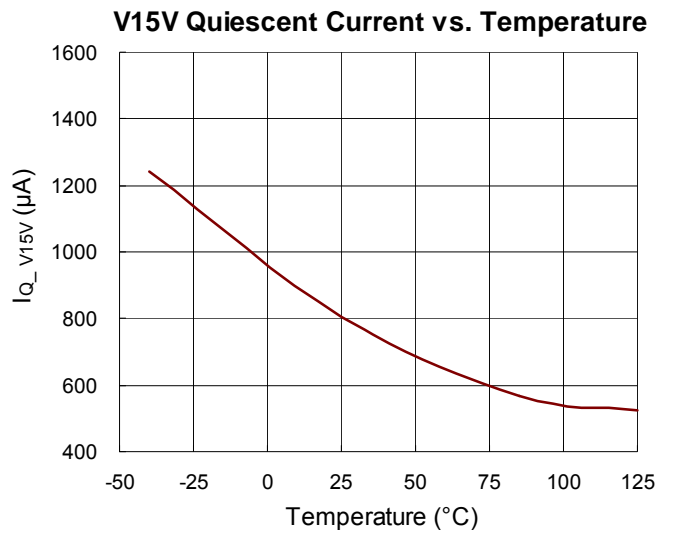
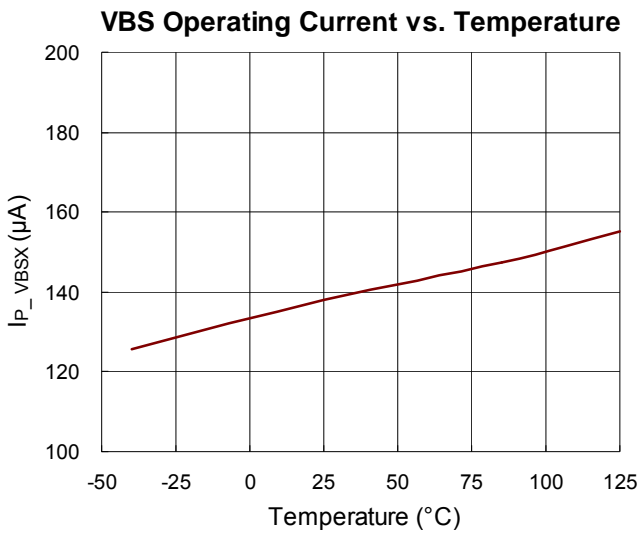
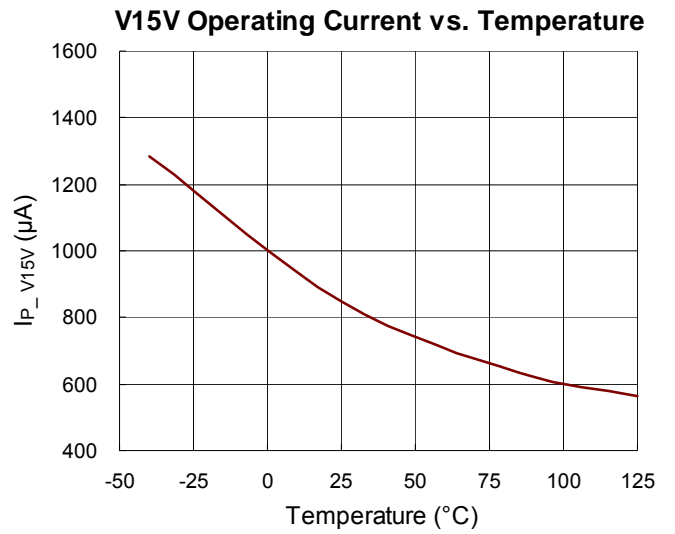
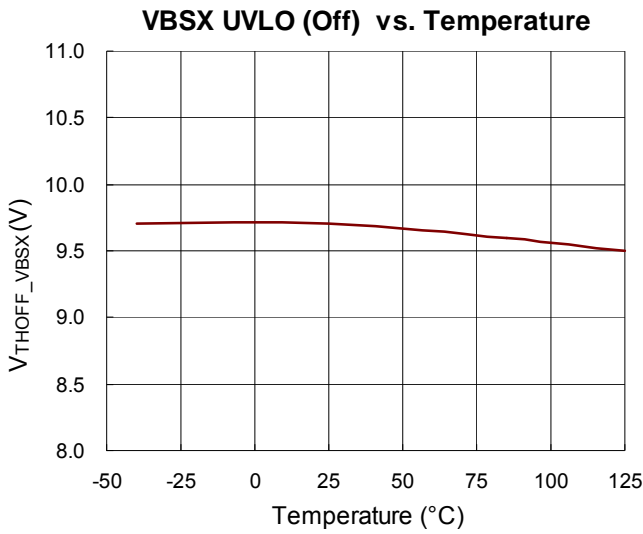


V15V UVLO (Off) vs. Temperature

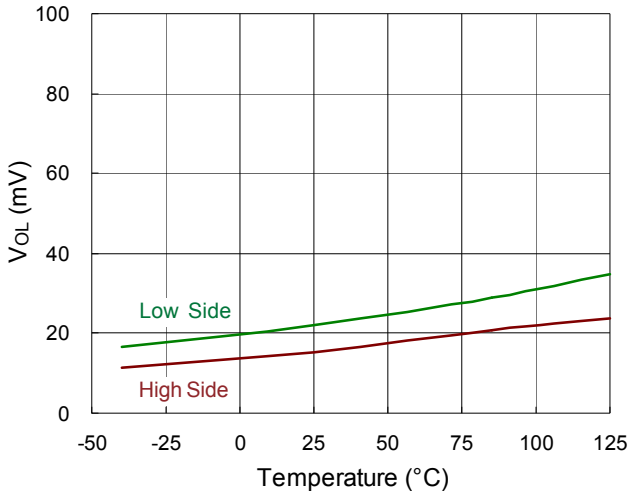


VBSX UVLO (On) vs. Temperature

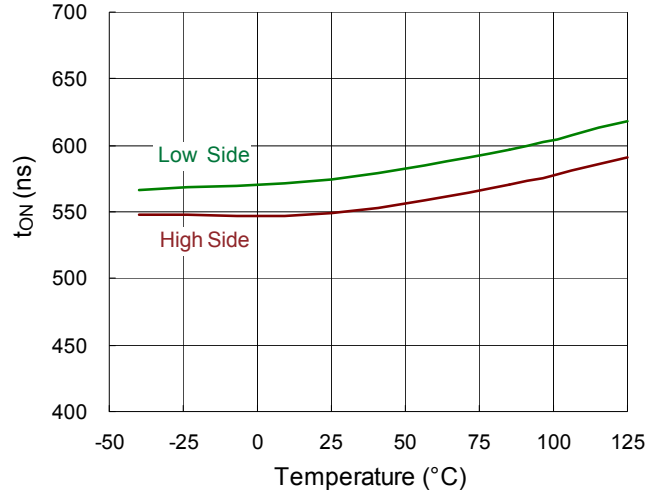




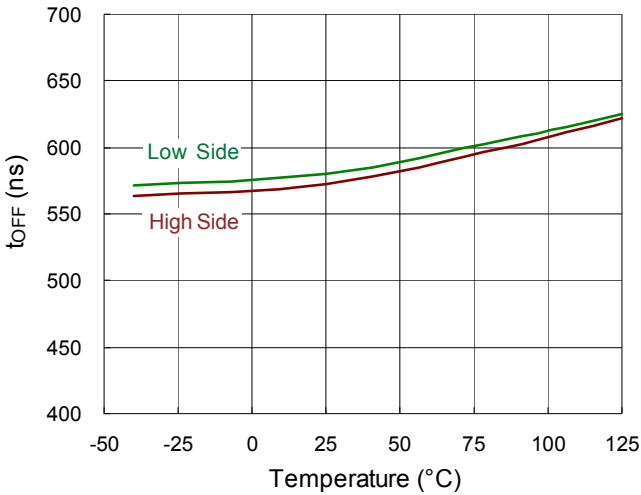
High/Low Side Output Voltage vs. Temperature



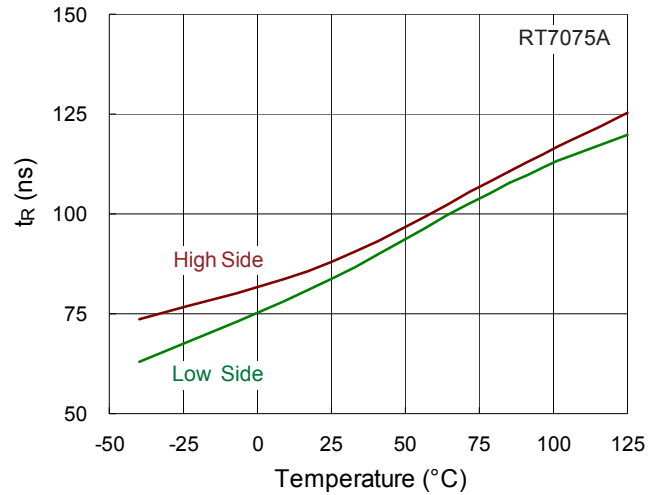
Turn-on Propagation Delay vs. Temperature



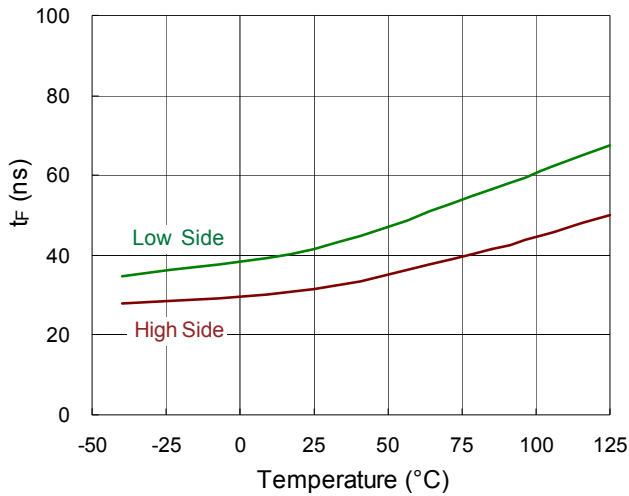
Turn-off Propagation Delay vs. Temperature



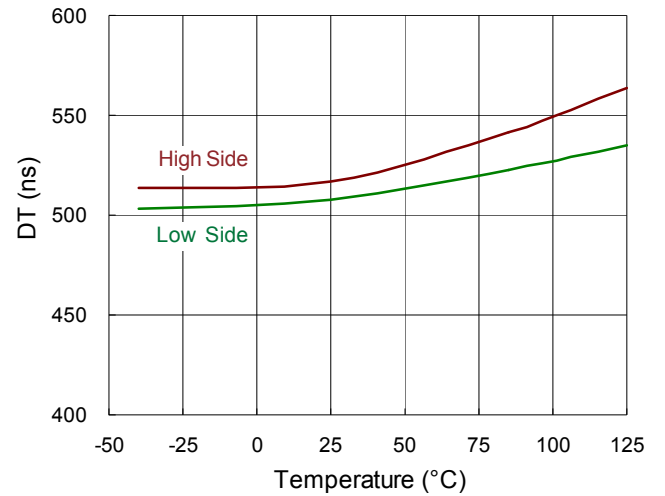
Turn-on Rising Time vs. Temperature

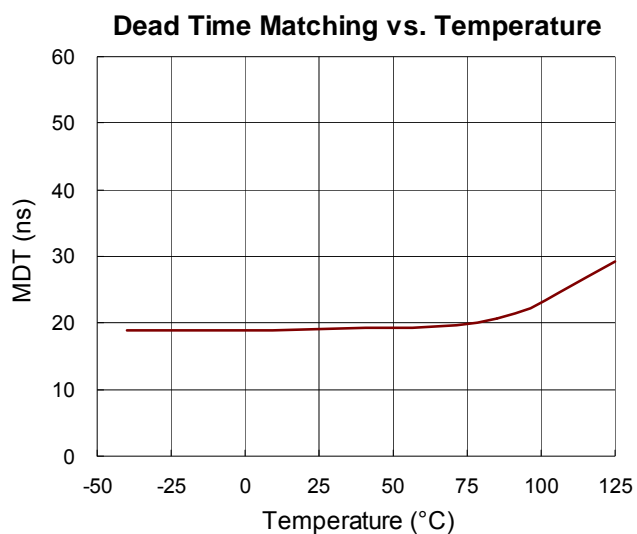
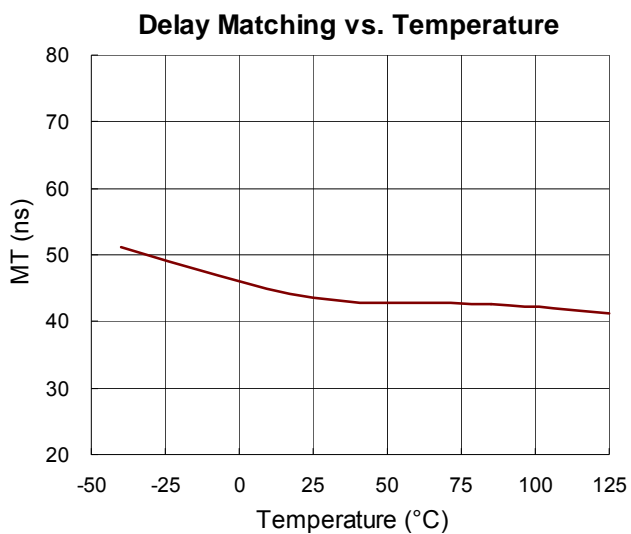


Turn-off Falling Time vs. Temperature



Dead Time vs. Temperature





Application Information

Dynamic Waveforms

Figure 1 is a definition of dynamic characteristics. You can know those definitions and the relationship between input and output from these figures. For example : t_{ON} , t_{OFF} , t_R , t_F , MT

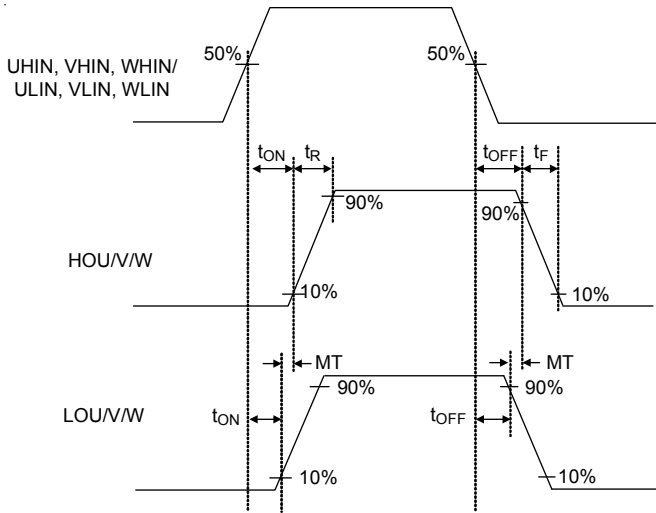


Figure 1. Dynamic Electrical Characteristics Definition

Deadtime

To avoid the simultaneous conduction of high-side and low-side power switches cause shoot through, the switching operation of the IC control circuit introduces a deadtime function. In the deadtime period, even if the input sends another power switch conduction signal, the control circuit will remain closed drive state. Figure 2 illustrates the definition of deadtime (DT_H & DT_L) and the relationship between the high-side and low-side gate signals.

Matched Propagation Delays

Because the IC internal level shifter circuit causes the propagation delay of the high-side output signal, the RT7075 add a propagation delay matching circuit in the low-side logic circuit, so that each high-side and low-side output signals (t_{ON} , t_{OFF}) approximately synchronization.

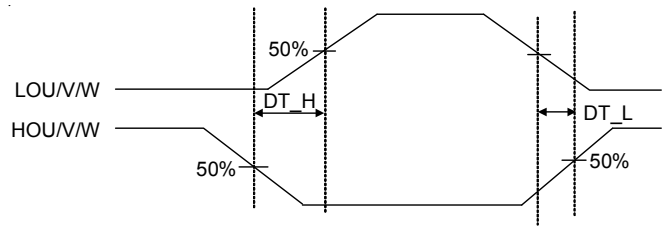


Figure 2. Deadtime Definition

Shoot-Through Protection

The RT7075 have shoot through protection circuitry to avoid the simultaneous conduction of high-side and low-side power switches cause shoot through, as shown Figure 3.

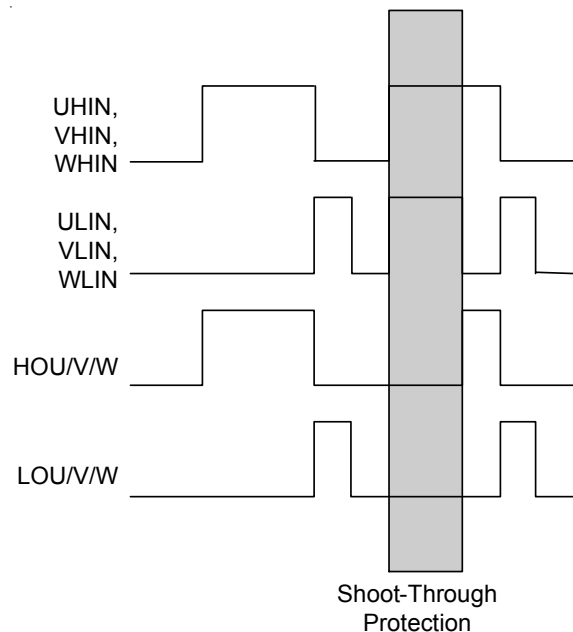


Figure 3. Shoot Through Protection

Thermal Considerations

The junction temperature should never exceed the absolute maximum junction temperature $T_{J(MAX)}$, listed under Absolute Maximum Ratings, to avoid permanent damage to the device. The maximum allowable power dissipation depends on the thermal resistance of the IC package, the PCB layout, the rate of surrounding airflow, and the difference between the junction and ambient temperatures. The maximum power dissipation can be calculated using the following formula :

$$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$$

where $T_{J(MAX)}$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction-to-ambient thermal resistance.

For continuous operation, the maximum operating junction temperature indicated under Recommended Operating Conditions is 125°C. The junction-to-ambient thermal resistance, θ_{JA} , is highly package dependent. For a LQFP-48L 7x7 package, the thermal resistance, θ_{JA} , is 67°C/W on a standard JEDEC 51-7 high effective-thermal-conductivity four-layer test board. The maximum power dissipation at $T_A = 25^\circ\text{C}$ can be calculated as below :

$$P_{D(MAX)} = (125^\circ\text{C} - 25^\circ\text{C}) / (67^\circ\text{C/W}) = 1.49\text{W for a LQFP-48L 7x7 package.}$$

The maximum power dissipation depends on the operating ambient temperature for the fixed $T_{J(MAX)}$ and the thermal resistance, θ_{JA} . The derating curves in Figure 4 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.

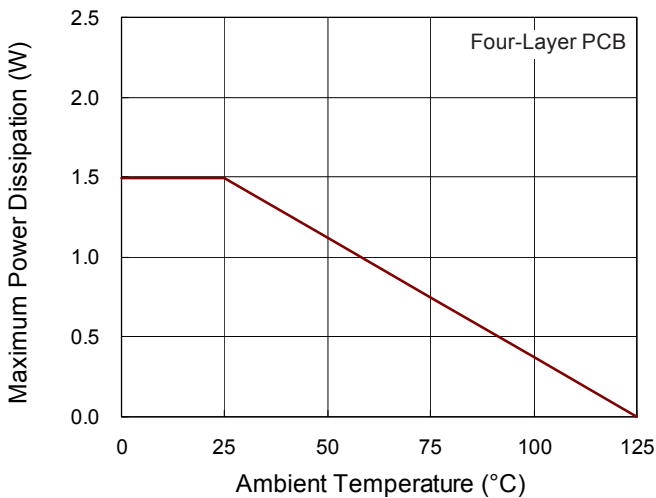
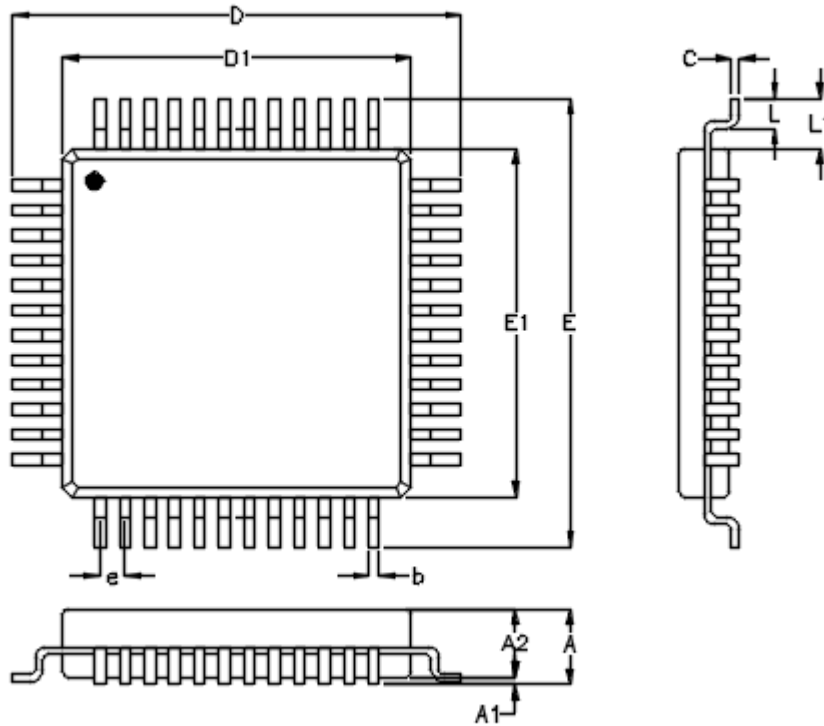


Figure 4. Derating Curve of Maximum Power Dissipation

Outline Dimension



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max.
A	1.400	1.600	0.055	0.063
A1	0.050	0.150	0.002	0.006
A2	1.350	1.450	0.053	0.057
b	0.170	0.270	0.007	0.011
C	0.090	0.200	0.004	0.008
D	8.800	9.200	0.346	0.362
E	8.800	9.200	0.346	0.362
D1	6.900	7.100	0.272	0.280
E1	6.900	7.100	0.272	0.280
e	0.500		0.020	
L	0.450	0.750	0.018	0.030
L1	0.800	1.200	0.031	0.047

L-Type 48-Lead QFP 7x7 Plastic Package

Richtek Technology Corporation

14F, No. 8, Tai Yuen 1st Street, Chupei City

Hsinchu, Taiwan, R.O.C.

Tel: (8863)5526789

Richtek products are sold by description only. Richtek reserves the right to change the circuitry and/or specifications without notice at any time. Customers should obtain the latest relevant information and data sheets before placing orders and should verify that such information is current and complete. Richtek cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Richtek product. Information furnished by Richtek is believed to be accurate and reliable. However, no responsibility is assumed by Richtek or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Richtek or its subsidiaries.